20th European Synchrotron Light Source Radio-Frequency Meeting PSI, November 16th-17th, 2016

STATE-OF-THE-ART RF SOLID STATE POWER AMPLIFIERS (SSPA's)

M. DIOP, on behalf of the RF group

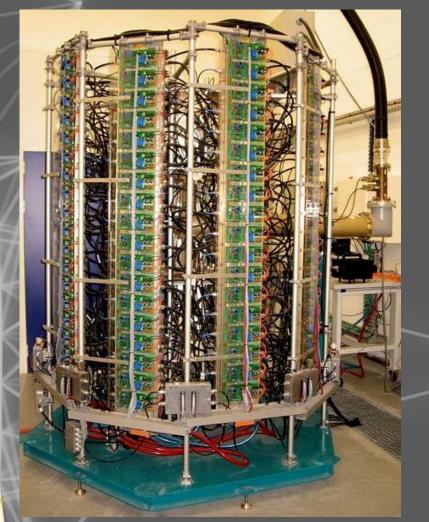
➢ Experience with the SOLEIL 352 MHz SSPA's
 ➢ R&D with SSPA's at SOLEIL → transfer of technology
 ➢ Review of used or planned SSPA's in other facilities

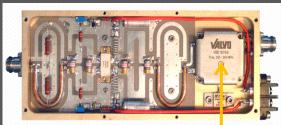




35 kW SSPA of the SOLEIL Booster

146 modules of 330 W @ 352 MHz with their individual power supplies, mounted on 8 water cooled dissipaters. All the components were designed in house and the series production contracted to the industry

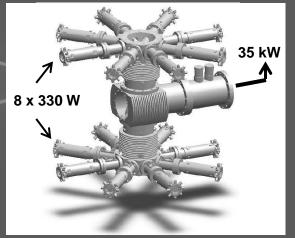




330 W CW - 352 MHz amplifier module **VDMOS D1029UK05** from SEMELAB (G = 11 dB, η = 62 %)

1 circulator per transistor : this is the key to success





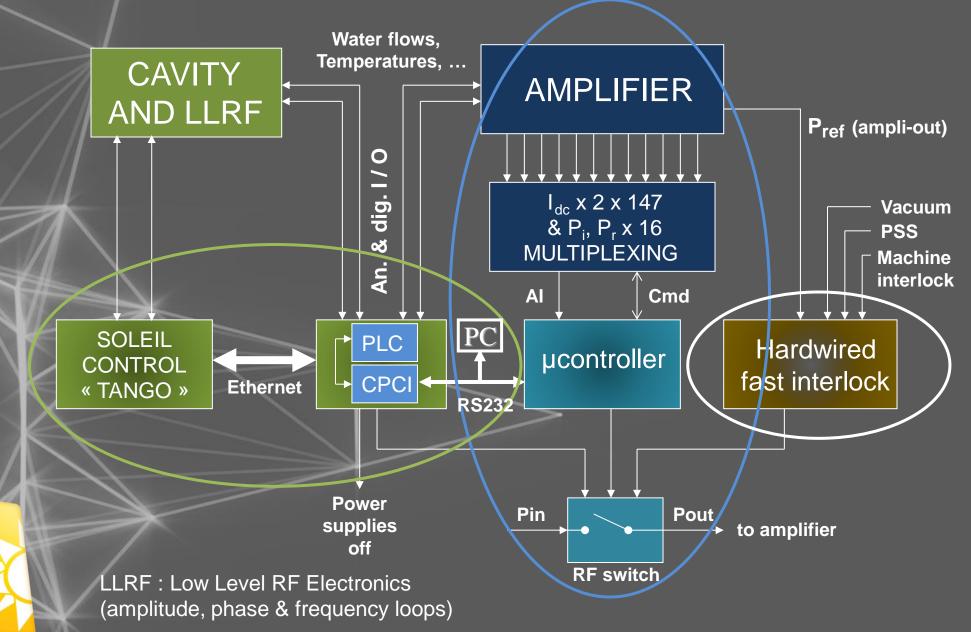
600 W - 280 / 28 V dc power converter

> Power combiner (8 x 8 x 2) 8 dissipaters of $16 + 2^*$ modules * driver amplifiers

~ 60 000 running hours over 10 years operation: only one single trip from the 35 kW SSPA in September 2016 due to a loose connection on a monitoring cable.



Booster RF control system

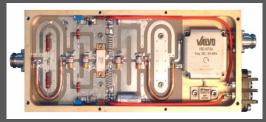




SOLEIL SR 180 kW SSPA's

Same principle as for the BO one, extended to 4 towers of 45 kW \rightarrow 10 dissipaters of 18 modules per tower \rightarrow 726 modules / amplifier x 4 cavities \rightarrow 16 towers & ~ 3000 modules

Amplifiers 1 & 2 (2 x 4 towers) powering the 2 cavities of Cryomodule 1 LDMOS LR301 from POLYFET G : 13 dB, η : 62 %





600 W - 280 Vdc / 28 Vdc





All the amplifier components were designed in house & the series production contracted to the industry



SR SSPA control

Multiplexing (I x 2 x 680 mod. + $P_i \& P_r x 80$) \rightarrow single µcontroller for 1 complete amplifier (4 towers)

🗊 SUPERVISION AMPLI RF Version du 30/08/2016													
Fichier Edition Outils											Tower T4 of		
			D1 Preampli	D2	D3 Vreampli	D4	D5 Preampli	D6	D7 Preampli	D8	D9 Preampli	D10	Amplifier 2
L.			7.00 6.40	0.00 0.00	6.40 7.40	0.00 0.00	6.50 6.30	0.00 0.00	6.60 7.00	0.00 0.00	6.80 6.80	0.00 0.00 M0	•
			7.40 7.50	7.30 7.40	7.10 7.10	7.10 7.10	7.00 7.10	7.20 7.20	7.00 6.90	7.40 7.50	7.20 7.30	7.20 7.20 M1	
			6.90 7.00	7.20 7.30	7.10 7.20	6.70 6.70	7.20 7.30	6.60 6.70	6.40 6.40	7.40 7.40	7.30 7.30	7.10 7.30 M2	
	AMPLI 1	(11)	7.10 7.20	7.20 7.20	6.80 6.90	7.00 7.00	7.00 7.20	7.30 7.30	7.10 7.40	7.40 7.30	7.10 7.30	7.30 7.20 M3	Тор
			7.00 6.90	7.20 7.30	6.90 0.00	6.90 7.00	7.10 7.10	7.10 7.10	7.00 7.00	7.30 7.40	7.10 7.30	7.30 7.40 M4	transistor
	AMPLI 2	<u>(12)</u>	7.30 7.40	7.40 7.30	7.10 7.10	6.60 6.80	7.10 7.20	6.80 6.80	6.60 6.50	7.10 7.20	7.60 7.50	7.20 7.30 M5	currents
	AMPLI 3	T3)	7.20 7.30	7.20 7.30	7.20 7.30	7.00 7.10	7.10 7.10	7.50 7.50	7.20 7.20	7.40 7.50	7.30 7.40	7.20 7.40 M6	Currents
F		ě	7.20 7.20	7.20 7.40	7.10 7.10	7.00 7.00	7.10 7.20	7.00 6.90	6.90 6.90	7.10 7.20	7.40 7.40	7.10 7.10 № 7	
_	AMPLI 4	(T4)	7.30 7.30	7.30 7.30	7.00 7.10	6.80 6.80	7.10 7.20	7.30 7.30	7.30 7.20	7.30 7.40	7.50 7.40	7.20 7.10 MB	
			1.42 0.00	1.48 0.00	1.10 0.00	1.74 0.00	1.48 0.00	1.40 0.00	1.44 0.00	1.38 0.00	1.58 0.00	1.48 0.00 Pi/Pr	Pi & Pr
			1.42 0.00	1.40 0.00	1.10 0.00	1.74 0.00	1.48 0.00	1.40 0.00	1.44 0.00	1.38 0.00	1.58 0.00	1.46 0.00 F1/F1	
╴													2.5 kW
	Aquisition O		1.44 0.00	1.62 0.00	1.66 0.06	1.60 0.12	1.34 0.02	1.42 0.08	1.54 0.10	1.48 0.08	1.62 0.08	1.54 0.04 Pi/Pr	combiners
Б			6.90 7.00	6.90 7.00	7.40 7.60	7.40 7.60	7.00 7.10	6.90 7.10	7.10 7.40	7.60 7.40	7.30 7.40	7.20 7.50 148	
	Messages	_	7.10 7.20	6.50 7.70	7.60 7.50	7.40 7.50	6.90 6.90	6.80 6.90	7.30 7.40	7.40 7.20	7.40 7.40	7.20 7.20 M7	
	D0		7.20 6.90	7.00 7.10	7.50 7.40	7.60 7.60	7.00 7.00	6.90 7.00	7.20 7.20	7.50 7.50	7.40 7.30	6.80 6.90 M6	Bottom
м1	✓ 0.30 0.	.30	7.00 7.10	6.80 6.90	7.60 7.60	7.60 7.50	7.00 7.10	6.90 6.90	7.20 7.20	7.40 7.40	7.30 7.20	7.40 7.30 M5	transistor
м2	☑ 0.50 0.	.60	7.20 7.30	6.90 7.00	7.40 7.60	7.60 6.70	7.10 7.20	7.00 7.10	6.80 6.90	7.10 7.30	7.30 7.30	7.30 7.40 M4	
мз	✓ 1.20 1.	.30	7.10 7.20	7.30 7.30	7.30 7.40	7.50 7.50	6.90 6.80	6.50 6.60	7.10 7.20	7.40 7.40	7.20 7.10	7.40 7.30 ^{M3}	currents
м4	1.00 1.	.30	7.00 7.20	7.10 7.10	7.50 7.50	7.60 7.70	7.00 7.20	6.80 6.80	7.30 7.20	7.00 7.30	7.30 7.40	7.40 7.50 M2	
М5	☑ 1.30 1.	.30	6.80 6.90	6.80 6.80	7.40 7.60	7.60 7.60	7.00 7.00	6.40 6.30	7.40 7.50	7.60 7.50	7.50 7.50	7.40 7.30 M1	
м6	0.00 0.	.00	0.00 0.00	7.10 6.60	0.00 0.00	7.20 6.40	0.00 0.00	6.70 6.00	0.00 0.00	7.10 6.60	0.00 0.00	7.30 6.60 M0	
			Preampli	🔽 Preampli	Preampli	Preampli	Preampli	Preampli	Preampli	Preampli	Preampli	Preampli	
				AMPLI	2		217- 200-						
	$\mathbf{D} = 1$	15 2 1				249 7 1/14	ω 175-				- III		
	F1-11	Pi = 115.2 kW Pr = 1.8 kW P Alim = 249.7 kW											
	TOUR 1	TOUR 1 TOUR 2 TOUR 3 TOUR 4				ື້ 125- ອີ 100-							
	Pi = 27.8	Pi = 27.80 kW Pi = 28.42 kW Pi = 29.22 kW Pi = 29.76 kW			2 75- 2 50-								
	Pr = 0.58	Pr = 0.58 kW Pr = 0.30 kW Pr = 0.30 kW Pr = 0.58 kW									lilili).		
	Pdc = 62	Pdc = 62.34 kW Pdc = 62.09 kW Pdc = 62.15 kW Pdc = 63.07 kW											
		Nombre de modules HS : 4						1.0 1.5 2.0 2.5	3.0 3.5 4.0 4		6.5 7.0 7.5 8.0	8.5 9.0 9.5 10.0	
Courant (A)													



SR SSPA's operational experience

Beam downtime caused by failures from the SR SSPA's over ~ 60 000 running hours in ~ 10 years

Equipment	Downtime	Comments
a) 4 x RF amplifiers	~ 1 10 ⁻⁴	 ~ 6 h in 5 short events due to preamplifiers MTBF > 10 000 h (cumulated by 4 amplifiers)
b) 4 x 500 kVA power supplies (230 Vac / 270 Vdc rectifiers)	~ 4 10 ⁻⁴	~ 23 h in 6 faults from the power supply control
a) + b) = 4 x RF transmitters	~ 5 10 ⁻⁴	MTBF ~ 5 000 h (cumulated by 4 transmitters)



Already excellent operational avaibility and MTBF, but still perfectible → Improvements brought in our new generation of amplifiers :

- ➢ Replace modular dc/dc converters + single ac/dc rectifier by modular ac/dc converters, in 2 kW units, directly connected on the mains → redundancy
- Use a "<u>combiner-divider</u>" in order to cure the lack of redundancy in the preamplification stage

The failure rate of our original LR301 transistors remains rather high, ~ 2-3% a year Thanks to the redundancy, the operation is not affected (except for preamplifiers) It is mainly a matter of maintenance : ~ 5 k€ of material + 3 men.week / year \rightarrow Largely improved with the <u>6th generation transistors</u> (Vd : 50 V instead of 30 V)

- ESRF experience with BLF578 transistors shows a huge reduction in failure rate Not yet a single one after ~ 4 years of operation with ~ 1 800 transistors !!
- > The refurbishment of the SOLEIL SSPA's with BLF574 transistors is in progress



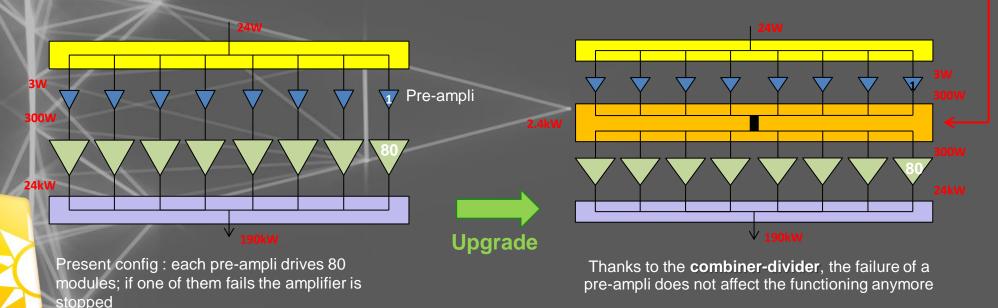
Upgrade of the SOLEIL SR SSPA's

Take advantage of using a transistor of 6th generation, the BLF574XR from NXP, which is much more robust and has higher performance than the LR301 \rightarrow Low cost upgrade

Change only the transistor + "module retuning", re-use old PCB \rightarrow ~ 10% of amplifier cost

- \rightarrow Electrical power savings (efficiency : 50 % \rightarrow 60%) compensate the investment cost in < 3 years
 - + 7 dB transistor gain \rightarrow 160 preampli modules & their dc PS are got back for the new BO SSPA
 - + More robust transistor & lower thermal stress \rightarrow much less module failures \rightarrow less maintenance
 - + Higher power capability (max P_{mod} : 310 W \rightarrow 450 W) \rightarrow 500 mA with only 3 running SSPA's

The first SSPA (4 towers) has now been upgraded \rightarrow 5th tower in mid-2017 \rightarrow go on at a rate of 1 - 2 towers a year Not a single failure of a « new » transistor until now (~ 2 years of operation)



Cure the lack of redundancy in the pre-amplification stage \rightarrow develop a "<u>combiner-divider</u>"



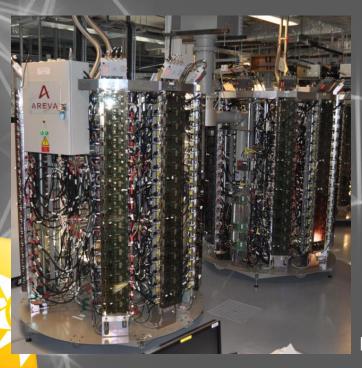
SOLEIL R&D with SSPA → Transfers of technology



SOLEIL R&D with 352 MHz SSPA's

Development of new RF modules, based on 6th generation LDMOS (Vd = 50V)
→ P_{mod} ~ 700 W, G ~ 20 dB, η > 70% at 352 MHz
[With original LR301 (28V), P_{mod} = 315 W, G = 13 dB, η = 62 % @ 352 MHz]
→ Huge improvement : P_{mod} x 2.2, better performance (G, η, linearity)
& thermal stress strongly reduced (ΔT : - 60 °C) → longer lifetime

ESRF upgrade → Replace 1 MW klystrons by 150 kW SSPA's (1 per cavity) → 2009, SOLEIL transfer of technology with ELTA-AREVA → 7 SSPA's of 150 kW, built by ELTA under SOLEIL license



BO : 4 x 150 kW SSPA's in use since January 2012 2 trips in ~ 5 years of operation → refill postponed
SR : 3 x 150 kW SSPA's in use since October 2013 2 trips in ~ 3 years of operation → beam loss
Trips, due to youth problems, which are now fixed
BO + SR : ~ 1 800 transistors → not a single failure !

Efficiency (dc to RF) : 58% (dc-dc converters) With new ac-dc converters $\rightarrow \eta$ (overall ac to RF) > 60%

ESRF 150 kW 352 MHz SSPA from ELTA/SOLEIL



LNLS - SOLEIL collaboration

Two SSPA's of 50 kW @ 476 MHz for LNLS (Brazilian LS) SR with components designed by SOLEIL (400 W modules with BLF574)



April 2010 in Campinas-Brazil : the SOLEIL - LNLS team, after successful tests of the amplifiers



LNLS 50 kW RF plants



The two 50 kW SSPA's have run satisfactorily on the LNLS SR for ~ 6 years → Use of SSPA's (500 MHz) for SIRIUS, their new light source

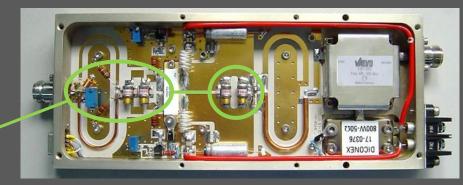


R&D with 500 MHz SSPA at SOLEIL

Experience feedback \rightarrow 1) Increase effort on the modularity/redundancy and the efficiency * 2) Moderate power for long lifetime (thermal stress \rightarrow soldering degradation) * + 10 pts in efficiency lead to electrical power savings over 10 years of operation \approx full amplifier cost

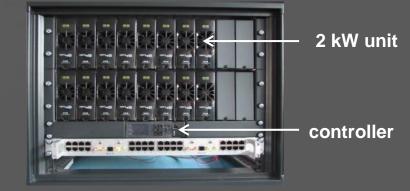
New 650 W - 500 MHz modules using 6th generation (Vd : 50V) LDMOS BLF578 from NXP

- ✤ RF output power, P_n: 650 W CW
- Input return loss : 40 dB at P_n
- Unconditional stability (K >10 dB)
- \diamond Gain : 17 dB at P_n (1dB compression)
- ♦ Efficiency \approx 62 % at P_n
- 🌺 Gain dispersion : +/- 0.2 dB at P_n Phase dispersion : +/- 5° at P_n



This is mandatory for good combining efficiency \rightarrow Components for gain and phase adjustments

Modular dc-dc converters + single power rectifier replaced by modular 230 V_{ac} / 50 V_{dc} converters, in 2 kW units, 96% efficiency, voltage remote control \rightarrow optimized efficiency for any operating power : 56% (overall) @ P_{max} and 50% @ 0.6 P_{max}



Modularity brought in the preamplification stage by inserting the « divider-combiner »



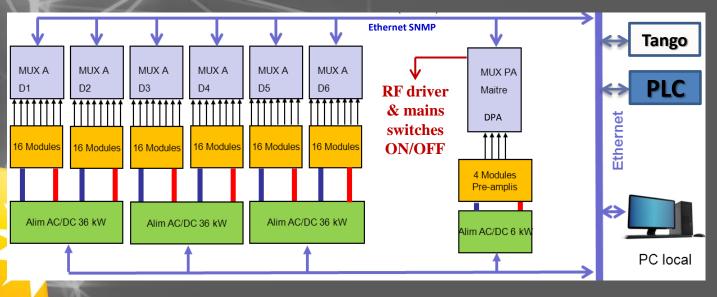
R&D with 500 MHz SSPA at SOLEIL

 Change from tower to cabinet assembly, better suited with the <u>new power supplies</u> while keeping the exchangeability at the lowest level, i.e. the elementary module

 optimum <u>modularity</u> / <u>redundancy</u> and spare inventory management

> 50 kW SSA for ThomX (6 dissipaters x 16 mod)

Improved control and supervision





80 kW SSA for SESAME (10 dissipaters x 16 mod)

1 MUX per dissipater MUX : analogic comparators & multiplexers + a µcontroller which monitors all data from a dissipater (16 mod & their PS) + CPLD for the interlocks

→ Fully stand-alone & self-protected



Other SOLEIL SSPA projects

We've completed the ThomX and first SESAME SSA's; the 3 other ones for SESAME are being built by SigmaPhi Electronics (SPE), the SOLEIL licensee

- ❑ The 150 kW-500 MHz SSA is already in the SPE catalogue
 → 2 x 75 kW (2 x 8 dissipaters of 16 modules) combined by means of a wave guide to coaxial combiner, the <u>WaCCo</u>
- 2 x 60 kW 186 MHz SSPA's for the LUNEX5 photocathode gun
 900 W RF modules using circulators, developped with Valvo

 □ 1.3 GHz SSA for LUCRECE (R&D for LUNEX5) SPE has already built SSA's at 1.3 GHz (P_{mod} ~ 200 W) 9 x 10 kW for ELBE & 1 x 16 kW for bERLinPro
 SOLEIL - SPE → 20 kW - 1.3 GHz SSA , P_{mod} > 400 W using <u>GaN transistor</u>

> Essential for higher frequency

SOLEIL upgrade towards DLSR and <u>VSR</u>

- \rightarrow harmonic cavities 1.76 GHz (h = 5) & 1.94 GHz (h = 5.5)
- \rightarrow 10 kW SSAs using GaN transistors





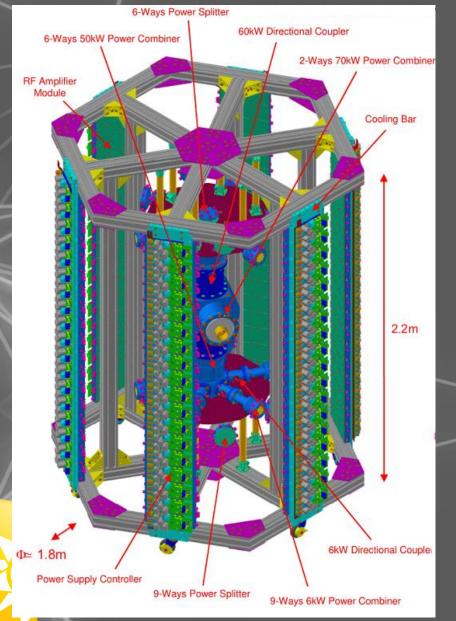
WaCCo



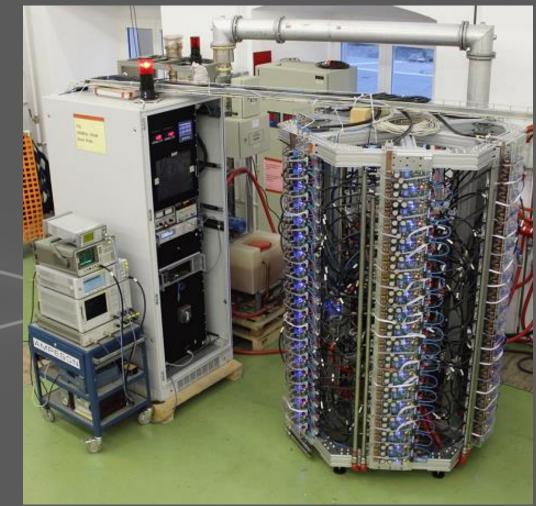
Used or planned SSPA's in other facilities



PSI 60 kW - 500 MHz SSPA



Home made, following the SOLEIL 352 MHz design but specificity of the control system Under test → Replace SLS Booster klystron



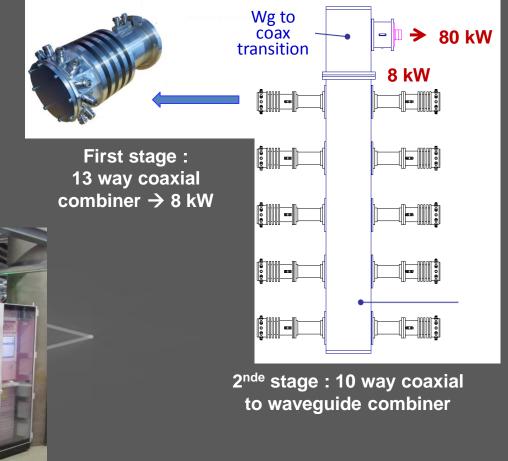


HZB - BESSY II 500 MHz SSPA's

At HZB, replacement of the BESSY II 500 MHz klystrons by SSPA's 4 x 80 kW (SR) + 1 x 40 kW (Booster), supplied by Cryoelectra GmbH

13 modules of 650 W + 1 driver per dissipater (x 10 dissipaters)





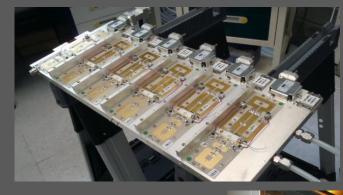
80 kW SR SSPA (efficiency ~ 50 %) 4 plants in operation since end 2015



R&D with cavity combiner for 352 MHz SSPA's at ESRF

The cavity is made of 22 water cooled "wings" On each wing, 6 modules of ~ 700 W Each module is magnetically coupled (loop) to the cavity





85 kW

Tests on prototype

"Fully planar" module efficiency ~ 65%
22 x 8 kW PS (1 / wing) in separate cabinet
At 85 kW drain efficiency : 64.5% ; 56% overall

PRO/CON

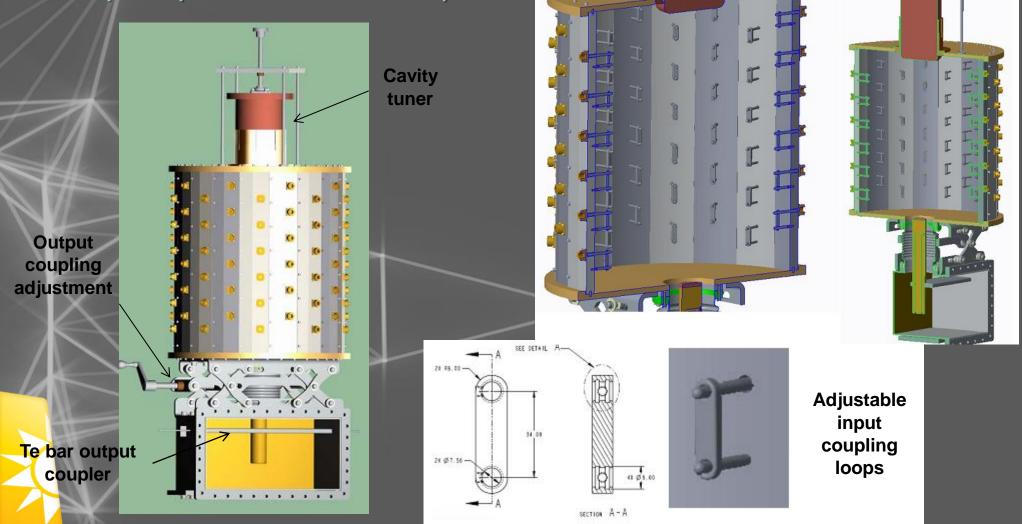
- (+) Eliminates power coaxial cables & more compact
- (-) Lower tolerable VSWR
- (-) "Narrow" bandwidth (~ 500 kHz)
- (-) Replacing a failing component \rightarrow remove a wing of 6 modules
- (-) Wing RF contacts on cavity body \rightarrow RF leaks (?)
- (-) Coupling dispersion \rightarrow individual loop size (or adjustment)





R&D with cavity combiner for 352 MHz SSPA's at APS

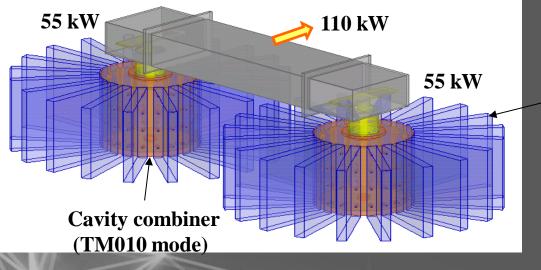
- Replace 1 MW 352 MHz klystron amplifiers with 200 kW SSPA's (1 / cavity)
- SSPA based on 2 kW LDMOS (Vd : 60 V) modules
- 108 : 1 cavity combiner (top & bottom plates + output coupler Te bar are water cooled)





R&D with cavity combiner for 500 MHz SSPA's at SPRING8

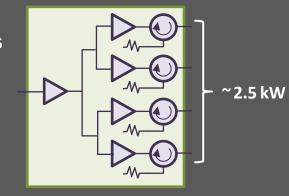
SPRING8 II → replace 1 MW - 500 MHz klystron amplifiers with 16 SSPA's of 110 kW (1 / cavity)

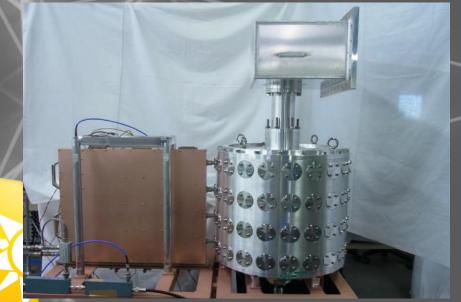


110 kW 500 MHz SSPA :

Combination of two 55 kW cavities 20 wings on each cavity Each SSA wing includes :

- 1 pre-amp
- 4 LDMOS
- 4 circulators





Prototype (only 1 wing) under low power tests

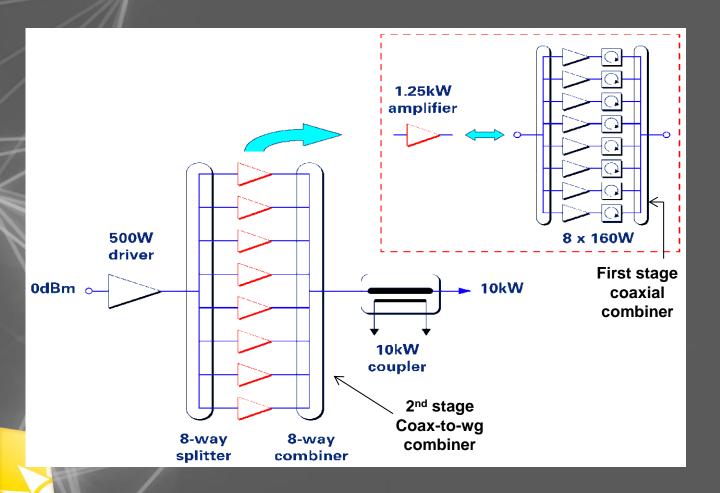
To limit the coupling dispersion, adjustment by loop rotation

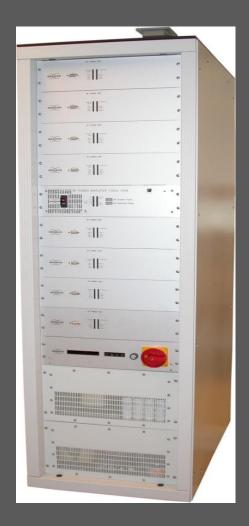




10 kW-1.3 GHz SSPA's for ELBE-HZDR

10 SSPA's of 10 kW @ 1.3 GHz supplied by Bruker, now SIGMAPHI ELECTRONICS, operational in ELBE at HZDR since beg. 2012 ; two 10 kW SSA's combined on one cavity

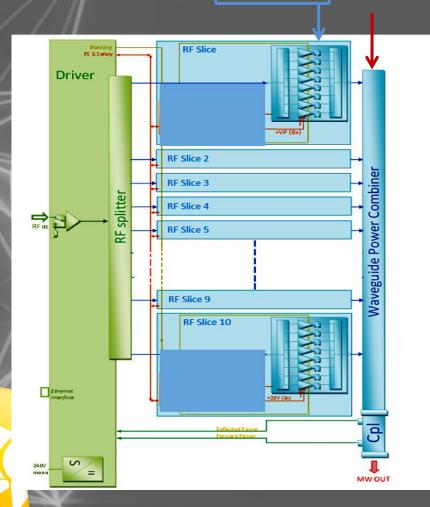






16 kW @ 1.3 GHz for BerlinPro - HZB

Upgraded version supplied by SIGMAPHI ELECTRONICS to HZB, intended to BerlinPro, presently used in HoBiCaT New generation transistor (50 V) \rightarrow ~ 200 W / module Power combination : 200 W x 8 x 10 \rightarrow 16 kW



16 kW - 1.3 GHz SSPA from SIGMAPHI ELECTRONICS



A similar one is being built by SPE for MESA



1.3 GHz - 3.8 kW SSA's for LCLS II

In SLAC LCLS II s.c. LINAC, need for 284 SSA's of 3.8 kW at 1.3 GHz

The 3.8 kW SSPA is based on 20 (or 24) LDMOS & circulators, combined with a coaxial combiner + 1 circulator at the output Prototypes from different suppliers

15 units already delivered6 more in OctoberThen delivery of 14 / month





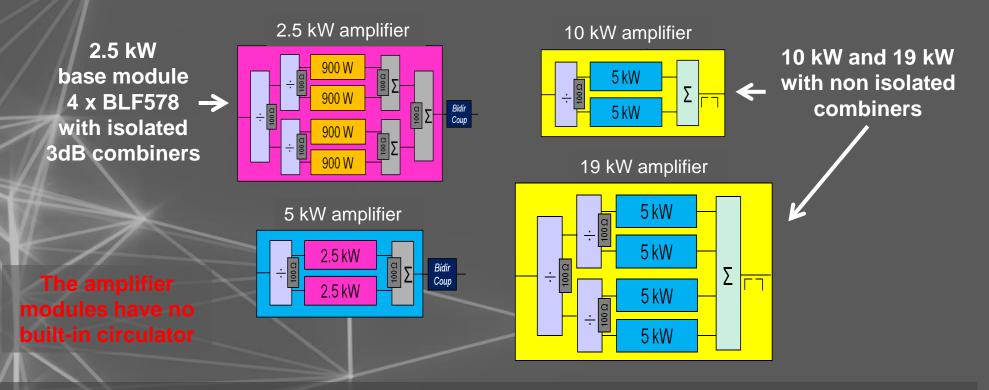
3.8 kW SSA from R&K Overall efficiency ~ 40%



GANIL - SPIRAL2 SSPA's @ 88 MHz

GANIL SPIRAL2 sc LINAC needs four types of 88 MHz amplifiers : $7 \times 2.5 \text{ kW}$, $2 \times 5 \text{ kW}$, $6 \times 10 \text{ kW}$ et $14 \times 19 \text{ kW}$

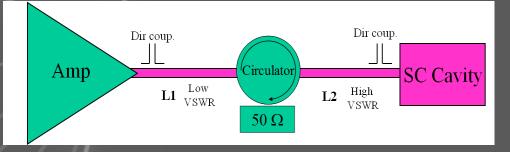
Use of SSPA's, supplied by BRUKER, now SIGMAPHI ELECTRONICS



UHF range (350 & 500 MHz, 1.3 GHz) \rightarrow Use of 1 circulator per transistor is the key to success At lower freq. difficult to build ~ 1 kW compact circulators \rightarrow FM - audio transmitter echnology (without circulator & with 3 dB hybrid combiners), well suited for medium power nto a matched load, but not for high power under mismatched conditions; the SSPA is very sensitive to VSWR !!



GANIL - SPIRAL2 SSPA's @ 88 MHz



- 1) Isolation and impedance of the power circulator significantly depends on the cavity operating conditions (VSWR in L2)
- 2) As the amplifier modules have no built-in circulator, the resulting VSWR in L1 is high enough to affect the amplifier performance

3) That requires adjusting L1 & L2 to limit $P_r < 4 \%$ (VSWR < 1.5) + oversizing of the amplifier in order to achieve the nominal power under any operating conditions



All the amplifiers have passed the SAT and are ready for the machine commissioning with cavities & beam. Overall efficiency ~ 66 %



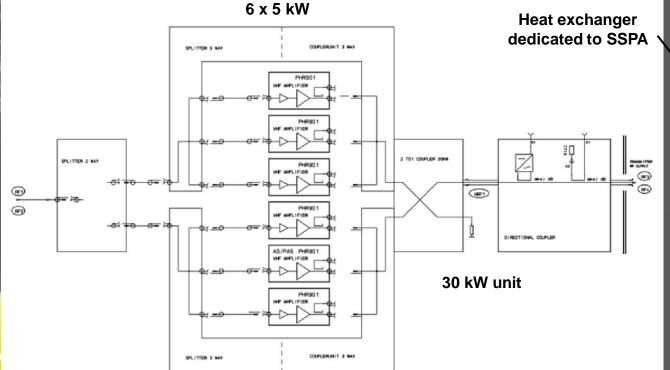
100 MHz SSPA's in MAX IV

SSPA's of 60 kW @ 100 MHz from Rhode & Schwarz

<u>1.5 GeV ring</u> : 2 cavities, each powered with a 60 kW SSPA *

<u>3 GeV ring</u> : 6 cavities, each presently powered with a 60 kW SSPA \rightarrow Phase 2 : 120 kW / cav from two 60 kW SSPA's, combined with 3 dB hybrid

Single high power circulator at the amplifier output



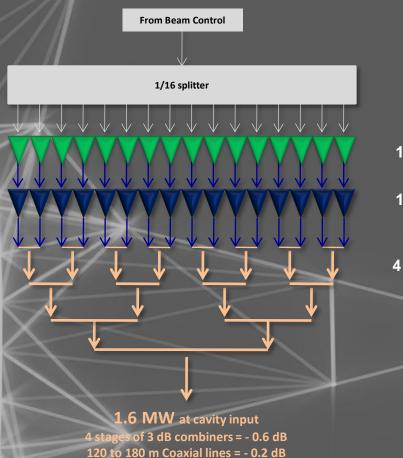


60 kW SSPA = 2 units of 30 kW combined with a 3 dB hybrid (efficiency ~ 66 %)

* Same thing in SOLARIS, which is a replica of 1.5 GeV - MAX IV

1.6 MW - 200 MHz SSPA's for CERN - SPS

CERN SPS needs for 1.6 MW peak (50% duty cycle) at 200 MHz x 2 cavities



YNCHROTRON



16 x 1.25 kW preamplifiers

16 x 140 kW amplifiers

4 stages of 3 dB hybrid coaxial combiners (as already existing)



140 kW SSPA from THALES 80 : 1 cavity combiner 80 x 2 kW RF units 2 transistors per unit First demonstrator delivery in Autumn 2016





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And many other ones, in use, in production or planned

ELETTRA : 1 x 20 kW - 500 MHz for the Booster, in production DELTA : 1 x 20 kW (booster) and 1 x 75 kW (SR) @ 500 MHz, in production CLS : 1 x 100 kW - 500 MHz for the Booster → call for tender DIAMOND : 1 x 80 kW - 500 MHz for the Booster + 1 x 60 kW - 500 MHz for test bench → call for tender ESS - Bilbao : 3 x 30 kW - 352 MHz for the buncher cavities of ESS → call for tender MYRRHA : 160 kW - 176 MHz (production) and 1 x 80 kW - 352 MHz (→ call for tender) SIRIUS : 4 x 60 kW - 500 MHz, planned ALBA : 4 x 30 kW - 1.5 GHz for 3rd harmonic system, planned FREIA - Uppsala : R&D with 10 kW - 352 MHz prototype (ESS operational conditions), in production IPNO - Orsay : 10 kW - 352 MHz prototype from LNL – INFN, used in EURISOL test bench IFMIF EVEDA : 18 x 200 kW - 175 MHz, planned

GANIL : 7 x 2.5 kW & 2 x 5 kW & 6 x 10 kW & 14 x 20 kW @ 88 MHz SESAME : 4 x 80 kW @ 500 MHz HZDR : 10 x 10 kW @ 1.3 GHz HZB : 1 x 15 kW @ 1.3 GHz MESA : 1 x 15 kW @ 1.3 GHz BARC (India) : 1 x 25 kW @ 75 MHz FERMILAB : 1 x 75 kW @ 162 MHz & 1 x 10 kW @ 325 MHz IAP Frankfort : 1 x 12 kW @ 176 MHz & 1 x 10 kW @ 88 MHz BNL : 1 x 20 kW @ 704 MHz JLAB : 1 x 10 kW @ 748 MHz TARLA (Turkey) : 2 x 4 kW @ 1.3 GHz

Built by SIGMAPHI ELECTRONICS



Summary - Conclusions

- SOLEIL has run for ~ 10 years with 352 MHz SSPA's (35 kW in the BO, 4 x 180 kW in the SR); they have shown an outstanding operational availability (MTBF >> 1 year). This experience has demonstrated that the SSPA can advantageously replace the vacuum tube in such an application, thanks to its inherent modularity/redundancy, the absence of HV and its <u>very low phase noise</u>.
- R&D carried out at SOLEIL allowed improving the original design towards more compactness in doubling the power per modules while reducing the thermal stress, improving the <u>redundancy</u> and the overall (plug to RF) <u>efficiency</u> up to 65 % (resp. 55 %) at 352 MHz (resp. 500 MHz).
- □ More recently, SOLEIL has built two 500 MHz SSPA's, one 50 kW for ThomX & one 80 kW for SESAME; 3 other identical ones are supplied to SESAME by SigmaPhi Electronics (SPE), the SOLEIL licensee ;
 - A 150 kW version is available as well.
- SSPA technology has now reached maturity ; SSPA's have run for a few years in several other places and the operational experience feedback is excellent :
 - 7 x 150 kW 352 MHz SSPA's from ELTA/SOLEIL, for 5 years in the ESRF BO (3 years in SR);
 - 2 x 50 kW 476 MHz SSPA's, realized within the frame of a collaboration between SOLEIL and LNLS -Brazil, for 6 years in the LNLS SR;
 - 10 x 10 kW 1.3 GHz SSPA, built by Bruker, now SPE, for 5 years in ELBE at HZD.

□ SSPA technology is being adopted by many other facilities and taken up by the industry for applications ranging from 80 MHz up to 1.5 GHz with power from few 10 kW up to MW. At f > 300 MHz, using a circulator per transistor is the key to success ; at lower frequency, the lack of ~ 1 kW compact circulators makes it less easy → VALVO - SOLEIL R&D with circulators. At f > 1.3 GHz, the GaN transistor supplants the LDMOS → SPE - SOLEIL R&D for LUCRECE.

R&D's are carried out with cavity combiners, which could be an alternative to coaxial combiners



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SOLEIL RF and LINAC group



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Thank you for your attention